



VN820 / VN820SO VN820SP / VN820-B5 / VN820PT

HIGH SIDE DRIVER

PRELIMINARY DATA

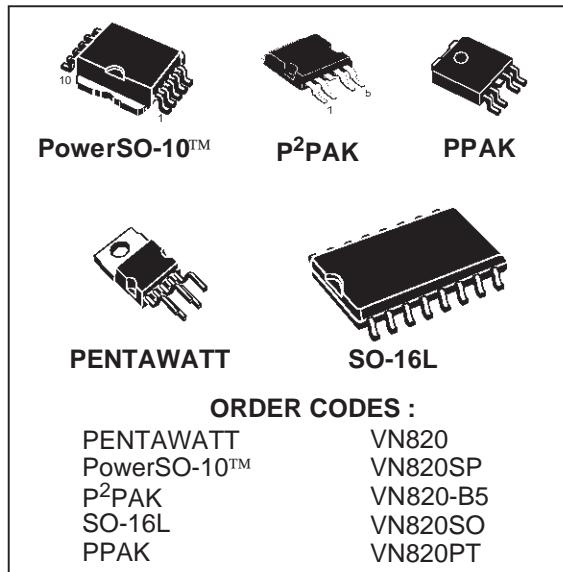
TYPE	R _{DS(on)}	I _{OUT}	V _{CC}
VN820			
VN820SP			
VN820-B5	40 mΩ	9 A	
VN820SO			
VN820PT			

- CMOS COMPATIBLE INPUT
- ON STATE OPEN LOAD DETECTION
- OFF STATE OPEN LOAD DETECTION
- SHORTED LOAD PROTECTION
- UNDervoltage AND OVERVOLTAGE SHUTDOWN
- PROTECTION AGAINST LOSS OF GROUND
- VERY LOW STAND-BY CURRENT
- REVERSE BATTERY PROTECTION (*)

DESCRIPTION

The VN820, VN820SP, VN820-B5, VN820SO, VN820PT are monolithic devices made by using STMicroelectronics VIPower M0-3 Technology, intended for driving any kind of load with one side connected to ground.

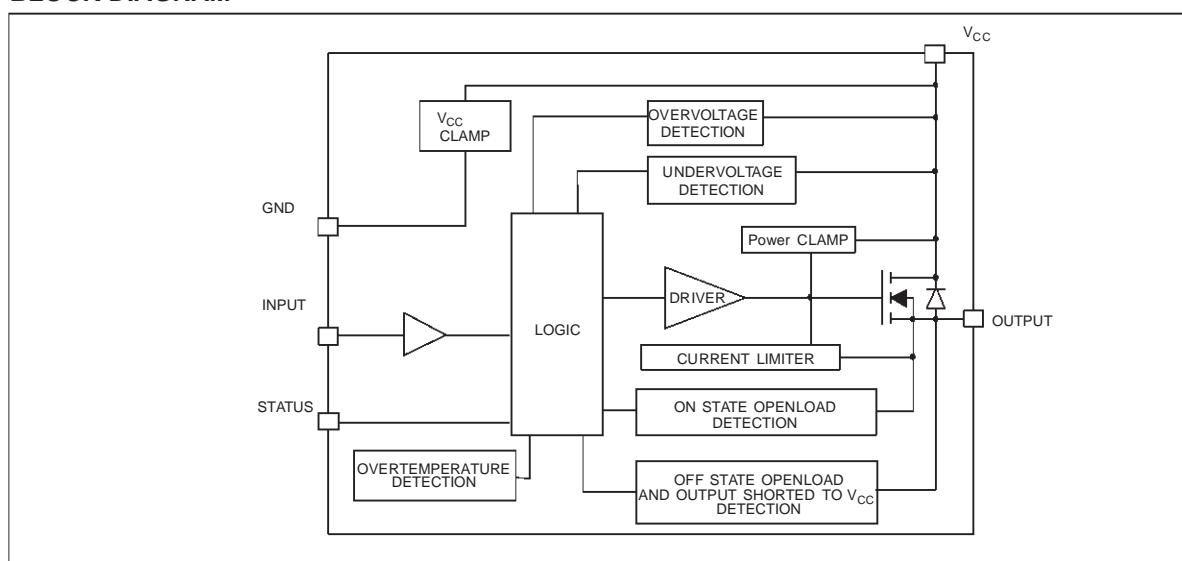
Active V_{CC} pin voltage clamp protects the device against low energy spikes (see ISO7637 transient



compatibility table). Active current limitation combined with thermal shutdown and automatic restart protect the device against overload.

The device detects open load condition both is on and off state. Output shorted to V_{CC} is detected in the off state. Device automatically turns off in case of ground pin disconnection.

BLOCK DIAGRAM



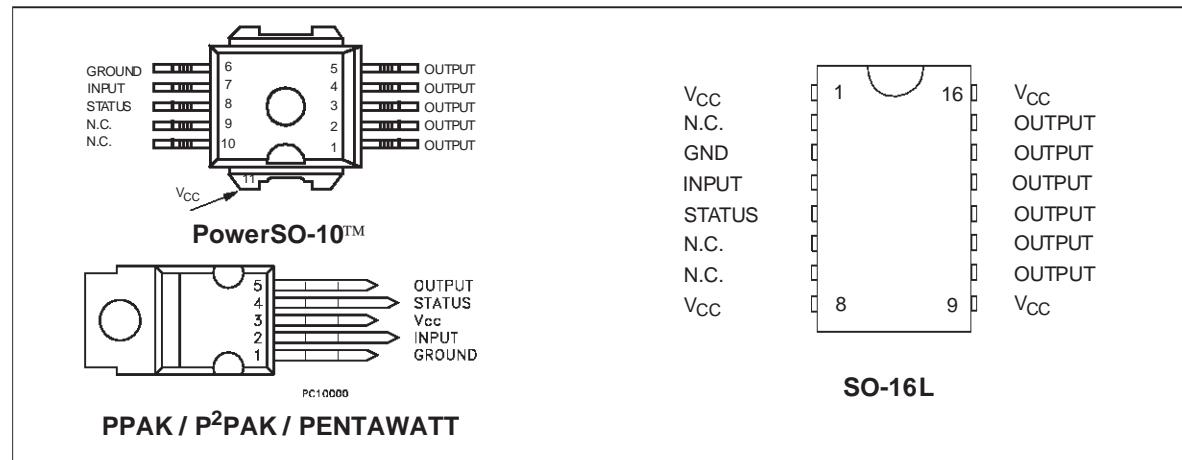
(*) See application schematic at page 8

VN820 / VN820SO / VN820SP / VN820-B5 / VN820PT

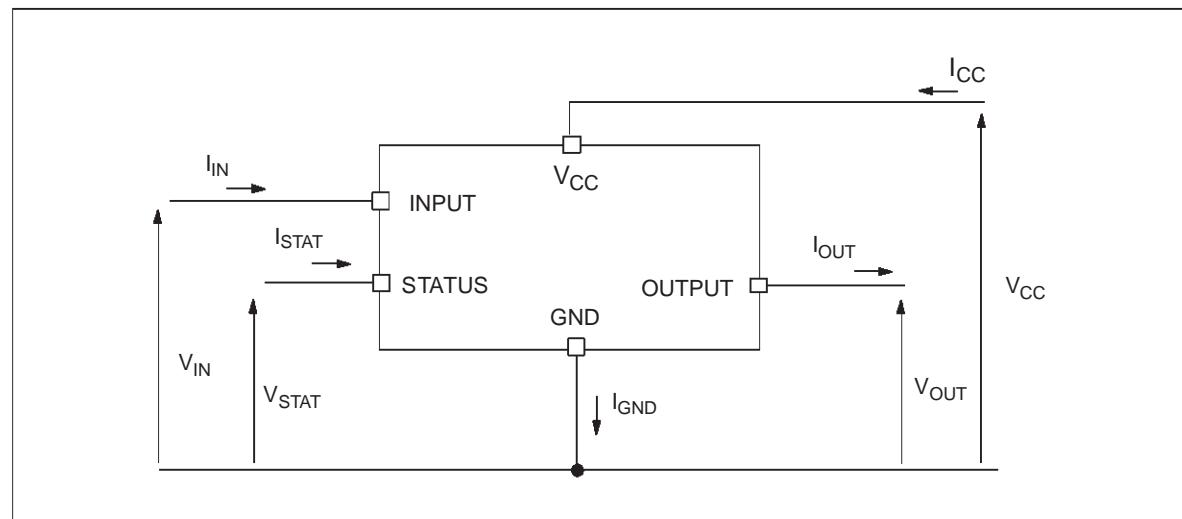
ABSOLUTE MAXIMUM RATING

Symbol	Parameter	Value					Unit
		PowerSO-10™	PENTAWATT	P ² PAK	SO-16L	PPAK	
V_{CC}	DC Supply Voltage		41				V
- V_{CC}	Reverse DC Supply Voltage		- 0.3				V
- I_{GND}	DC Reverse Ground Pin Current		- 200				mA
I_{OUT}	DC Output Current		Internally Limited				A
- I_{OUT}	Reverse DC Output Current		- 9				A
I_{IN}	DC Input Current		+/- 10				mA
I_{STAT}	DC Status Current		+/- 10				mA
V_{ESD}	Electrostatic Discharge ($R=1.5\text{ k}\Omega$; $C=100\text{ pF}$)		2000				V
P_{tot}	Power Dissipation $T_C=25^\circ\text{C}$	62.5	62.5	62.5	8.3	42	W
T_j	Junction Operating Temperature	Internally Limited					$^\circ\text{C}$
T_c	Case Operating Temperature	- 40 to 150					$^\circ\text{C}$
T_{stg}	Storage Temperature	- 55 to 150					$^\circ\text{C}$

CONNECTION DIAGRAM (TOP VIEW)



CURRENT AND VOLTAGE CONVENTIONS



THERMAL DATA

Symbol	Parameter	Value					Unit
		PowerSO-10™	PENTAWATT	P ² PAK	SO-16L	PPAK	
R _{thj-case}	Thermal Resistance Junction-case Max	2.0	2.0	2.0	-	3	°C/W
R _{thj-lead}	Thermal Resistance Junction-lead Max	-	-	-	15	-	°C/W
R _{thj-amb}	Thermal Resistance Junction-ambient Max	52 (*)	60 (*)	52 (*)	65 (**)	53 (*)	°C/W

(*) When mounted on a standard single-sided FR-4 board with 50mm² of Cu (at least 35µm thick).

(**) When mounted on FR4 printed circuit board with 50mm² of Cu (at least 35µ thick) connected to all V_{CC} pins.

ELECTRICAL CHARACTERISTICS (8V<V_{CC}<36V; -40°C<T_j<150°C unless otherwise specified)

POWER

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
V _{CC}	Operating Supply Voltage		5.5	13	36	V
V _{USD}	Undervoltage Shut-down		3	4	5.5	V
V _{USDhyst}	Undervoltage Shut-down hysteresis			0.5		V
V _{OV}	Oversupply Shut-down		36	42	48	V
R _{ON}	On State Resistance	I _{OUT} =3A; T _j =25°C; V _{CC} >8V I _{OUT} =3A; V _{CC} >8V			40 80	mΩ mΩ
I _S	Supply Current	Off State; V _{CC} =13V; V _{IN} =V _{OUT} =0V Off State; V _{CC} =13V; V _{IN} =V _{OUT} =0V; T _j =25°C On State; V _{CC} =13V; V _{IN} =5V; I _{OUT} =0A		10 10 2	25 20 3.5	µA µA mA
I _{L(off1)}	Off State Output Current	V _{IN} =V _{OUT} =0V	0		50	µA
I _{L(off2)}	Off State Output Current	V _{IN} =0V; V _{OUT} =3.5V	-75		0	µA

SWITCHING (V_{CC}=13V)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
t _{d(on)}	Turn-on Delay Time	R _L =4.3Ω from V _{IN} rising edge to V _{OUT} =1.3V		30		µs
t _{d(off)}	Turn-off Delay Time	R _L =4.3Ω from V _{IN} falling edge to V _{OUT} =11.7V		30		µs
dV _{OUT} /dt _(on)	Turn-on Voltage Slope	R _L =4.3Ω from V _{OUT} =1.3V to V _{OUT} =10.4V		0.3		V/µs
dV _{OUT} /dt _(off)	Turn-off Voltage Slope	R _L =4.3Ω from V _{OUT} =11.7V to V _{OUT} =1.3V		0.3		V/µs

INPUT PIN

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
V _{IL}	Input Low Level				1.25	V
I _{IL}	Low Level Input Current	V _{IN} =1.25V	1			µA
V _{IH}	Input High Level		3.25			V
I _{IH}	High Level Input Current	V _{IN} =3.25V			10	µA
V _{I(hyst)}	Input Hysteresis Voltage		0.5			V
V _{ICL}	Input Clamp Voltage	I _{IN} =1mA I _{IN} =-1mA	6	6.8 -0.7	8	V V

VN820 / VN820SO / VN820SP / VN820-B5 / VN820PT

ELECTRICAL CHARACTERISTICS (continued)

STATUS PIN

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
V_{STAT}	Status Low Output Voltage	$I_{STAT}=1.6\text{mA}$			0.5	V
I_{LSTAT}	Status Leakage Current	Normal Operation $V_{STAT}=5\text{V}$			10	μA
C_{STAT}	Status Pin Input Capacitance	Normal Operation $V_{STAT}=5\text{V}$			100	pF
V_{SCL}	Status Clamp Voltage	$I_{STAT}=1\text{mA}$ $I_{STAT}=-1\text{mA}$	6	6.8 -0.7	8	V V

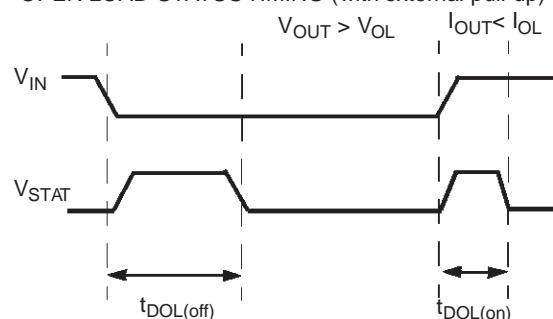
PROTECTIONS

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
T_{TSD}	Shut-down Temperature		150	175	200	$^{\circ}\text{C}$
T_R	Reset Temperature		135			$^{\circ}\text{C}$
T_{hyst}	Thermal Hysteresis		7	15		$^{\circ}\text{C}$
t_{SDL}	Status delay in overload condition	$T_j > T_{TSD}$			20	μs
I_{lim}	Current limitation	$5.5\text{V} < V_{CC} < 36\text{V}$	9	13 20	20	A A
V_{demag}	Turn-off Output Clamp Voltage	$I_{OUT}=3\text{A}$; $V_{IN}=0\text{V}$; $L=6\text{mH}$	$V_{CC}-41$	$V_{CC}-48$	$V_{CC}-55$	V

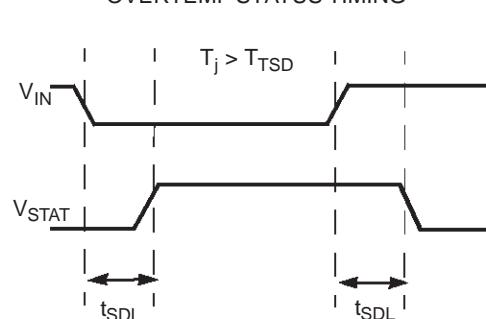
OPENLOAD DETECTION

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
I_{OL}	Openload ON State Detection Threshold	$V_{IN}=5\text{V}$	70	150	300	mA
$t_{DOL(on)}$	Openload ON State Detection Delay	$I_{OUT}=0\text{A}$			200	μs
V_{OL}	Openload OFF State Voltage Detection Threshold	$V_{IN}=0\text{V}$	1.5	2.5	3.5	V
$t_{DOL(off)}$	Openload Detection Delay at Turn Off				1000	μs

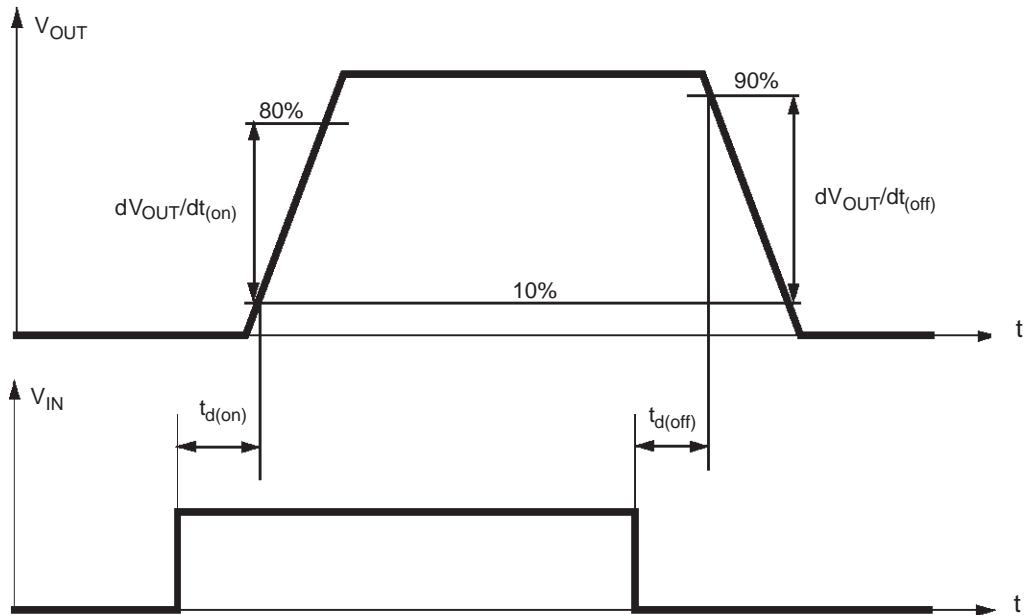
OPEN LOAD STATUS TIMING (with external pull-up)



OVERTEMP STATUS TIMING



Switching time Waveforms



TRUTH TABLE

CONDITIONS	INPUT	OUTPUT	STATUS
Normal Operation	L H	L H	H H
Current Limitation	L H	L X	H H
Overtemperature	L H	L L	H L
Undervoltage	L H	L L	X X
Overvoltage	L H	L L	H H
Output Voltage > V_{OL}	L H	H H	L H
Output Current < I_{OL}	L H	L H	H L

VN820 / VN820SO / VN820SP / VN820-B5 / VN820PT

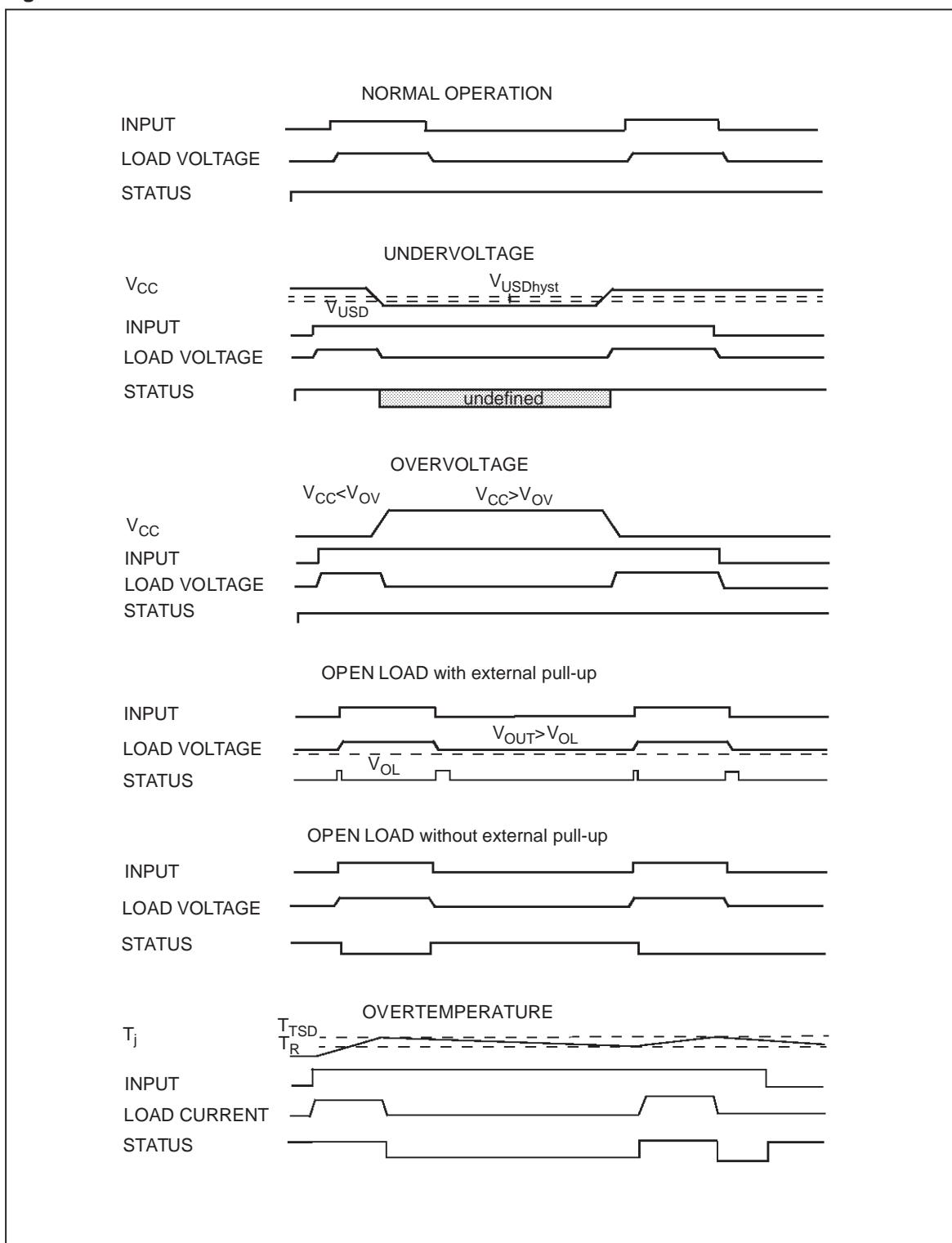
ELECTRICAL TRANSIENT REQUIREMENTS ON V_{CC} PIN

ISO T/R 7637/1 Test Pulse	TEST LEVELS				
	I	II	III	IV	Delays and Impedance
1	-25 V	-50 V	-75 V	-100 V	2 ms 10 Ω
2	+25 V	+50 V	+75 V	+100 V	0.2 ms 10 Ω
3a	-25 V	-50 V	-100 V	-150 V	0.1 μs 50 Ω
3b	+25 V	+50 V	+75 V	+100 V	0.1 μs 50 Ω
4	-4 V	-5 V	-6 V	-7 V	100 ms, 0.01 Ω
5	+26.5 V	+46.5 V	+66.5 V	+86.5 V	400 ms, 2 Ω

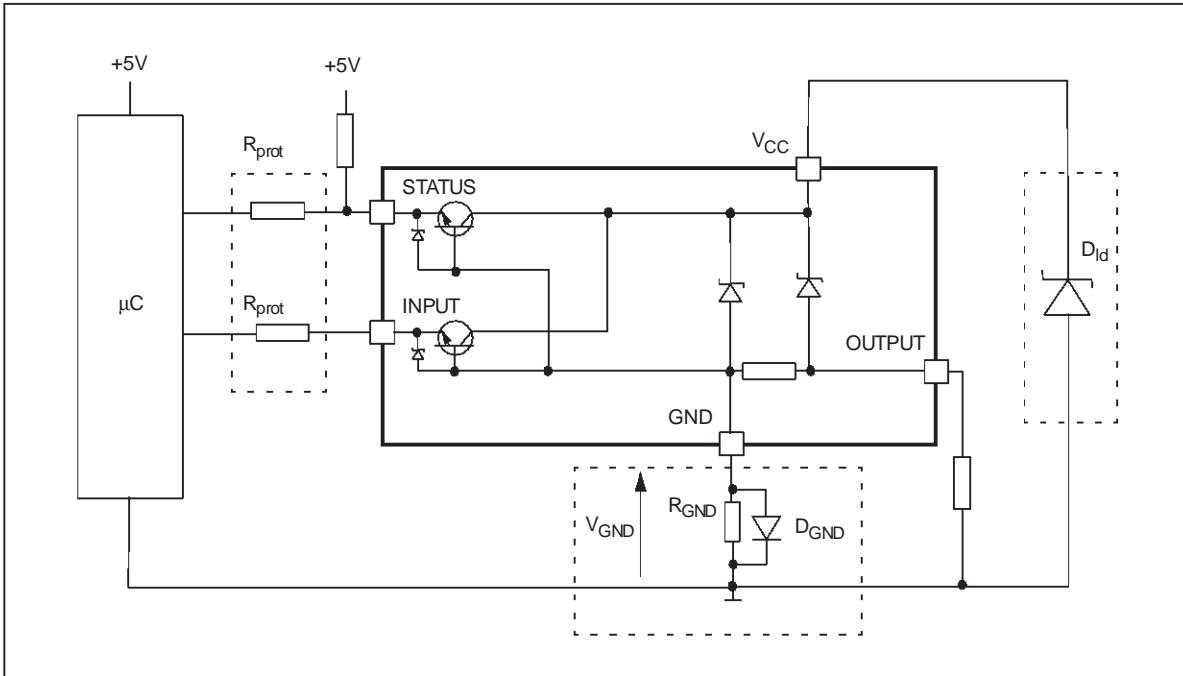
ISO T/R 7637/1 Test Pulse	TEST LEVELS RESULTS			
	I	II	III	IV
1	C	C	C	C
2	C	C	C	C
3a	C	C	C	C
3b	C	C	C	C
4	C	C	C	C
5	C	E	E	E

CLASS	CONTENTS
C	All functions of the device are performed as designed after exposure to disturbance.
E	One or more functions of the device is not performed as designed after exposure to disturbance and cannot be returned to proper operation without replacing the device.

Figure1: Waveforms



APPLICATION SCHEMATIC



GND PROTECTION NETWORK AGAINST REVERSE BATTERY

Solution 1: Resistor in the ground line (R_{GND} only). This can be used with any type of load.

The following is an indication on how to dimension the R_{GND} resistor.

- 1) $R_{GND} \leq 600\text{mV} / (I_{S(on)\max})$.
- 2) $R_{GND} \geq (-V_{CC}) / (-I_{GND})$

where $-I_{GND}$ is the DC reverse ground pin current and can be found in the absolute maximum rating section of the device's datasheet.

Power Dissipation in R_{GND} (when $V_{CC} < 0$: during reverse battery situations) is:

$$P_D = (-V_{CC})^2 / R_{GND}$$

This resistor can be shared amongst several different HSD. Please note that the value of this resistor should be calculated with formula (1) where $I_{S(on)\max}$ becomes the sum of the maximum on-state currents of the different devices.

Please note that if the microprocessor ground is not common with the device ground then the R_{GND} will produce a shift ($I_{S(on)\max} * R_{GND}$) in the input thresholds and the status output values. This shift will vary depending on many devices are ON in the case of several high side drivers sharing the same R_{GND} .

If the calculated power dissipation leads to a large resistor or several devices have to share the same resistor then the ST suggest to utilize Solution 2 (see below).

Solution 2: A diode (D_{GND}) in the ground line.

A resistor ($R_{GND}=1\text{k}\Omega$) should be inserted in parallel to D_{GND} if the device will be driving an inductive load.

This small signal diode can be safely shared amongst several different HSD. Also in this case, the presence of the ground network will produce a shift ($\pm 600\text{mV}$) in the input threshold and the status output values if the microprocessor ground is not common with the device ground. This shift will not vary if more than one HSD shares the same diode/resistor network.

LOAD DUMP PROTECTION

D_{Id} is necessary (Transil or MOV) if the load dump peak voltage exceeds V_{CC} max DC rating. The same applies if the device will be subject to transients on the V_{CC} line that are greater than the ones shown in the ISO T/R 7637/1 table.

μC I/Os PROTECTION:

If a ground protection network is used and negative transient are present on the V_{CC} line, the control pins will be pulled negative. ST suggests to insert a resistor (R_{prot}) in line to prevent the μ C I/Os pins to latch-up.

The value of these resistors is a compromise between the leakage current of μ C and the current required by the HSD I/Os (Input levels compatibility) with the latch-up limit of μ C I/Os.

$$-V_{CCpeak} / I_{latchup} \leq R_{prot} \leq (V_{OH\mu C} - V_{IH} - V_{GND}) / I_{IH\max}$$

Calculation example:

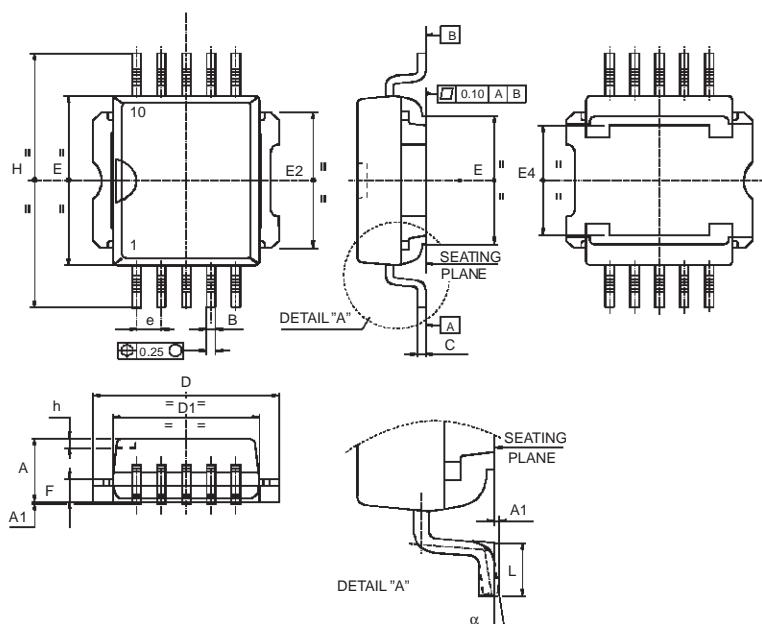
For $V_{CCpeak} = -100\text{V}$ and $I_{latchup} \geq 20\text{mA}$; $V_{OH\mu C} \geq 4.5\text{V}$
 $5\text{k}\Omega \leq R_{prot} \leq 65\text{k}\Omega$.

Recommended R_{prot} value is $10\text{k}\Omega$.

PowerSO-10™ MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	3.35		3.65	0.132		0.144
A (*)	3.4		3.6	0.134		0.142
A1	0.00		0.10	0.000		0.004
B	0.40		0.60	0.016		0.024
B (*)	0.37		0.53	0.014		0.021
C	0.35		0.55	0.013		0.022
C (*)	0.23		0.32	0.009		0.0126
D	9.40		9.60	0.370		0.378
D1	7.40		7.60	0.291		0.300
E	9.30		9.50	0.366		0.374
E2	7.20		7.60	0.283		300
E2 (*)	7.30		7.50	0.287		0.295
E4	5.90		6.10	0.232		0.240
E4 (*)	5.90		6.30	0.232		0.248
e		1.27			0.050	
F	1.25		1.35	0.049		0.053
F (*)	1.20		1.40	0.047		0.055
H	13.80		14.40	0.543		0.567
H (*)	13.85		14.35	0.545		0.565
h		0.50			0.002	
L	1.20		1.80	0.047		0.070
L (*)	0.80		1.10	0.031		0.043
α	0°		8°	0°		8°
$\alpha (*)$	2°		8°	2°		8°

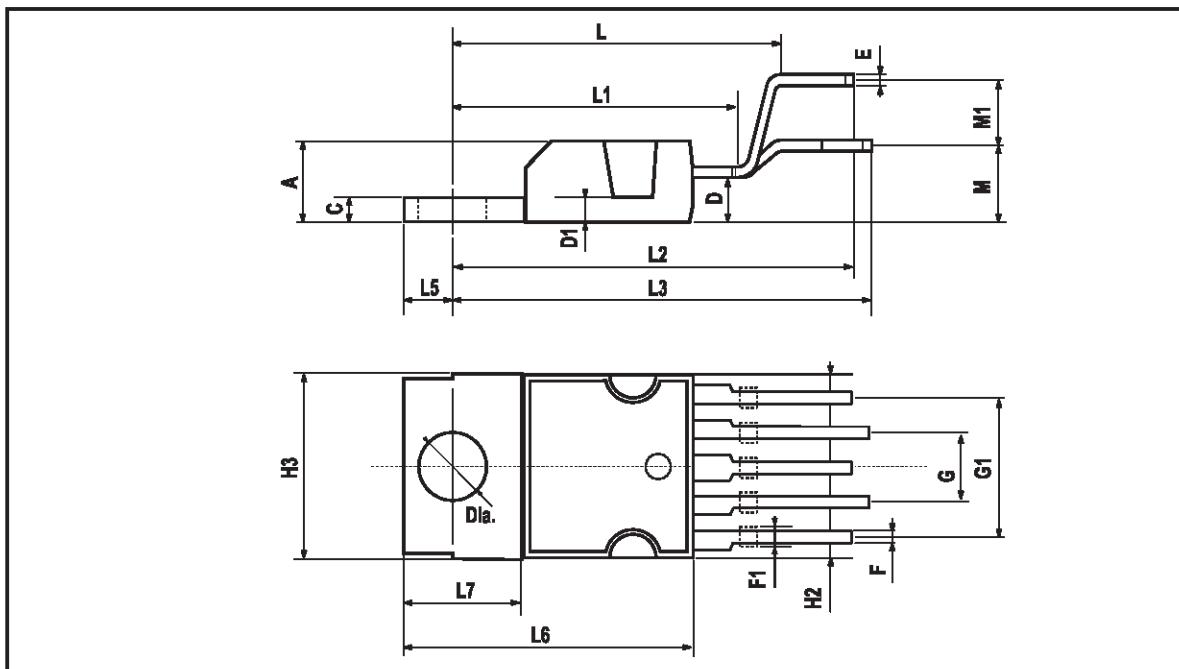
(*) Muar only POA P013P



P095A

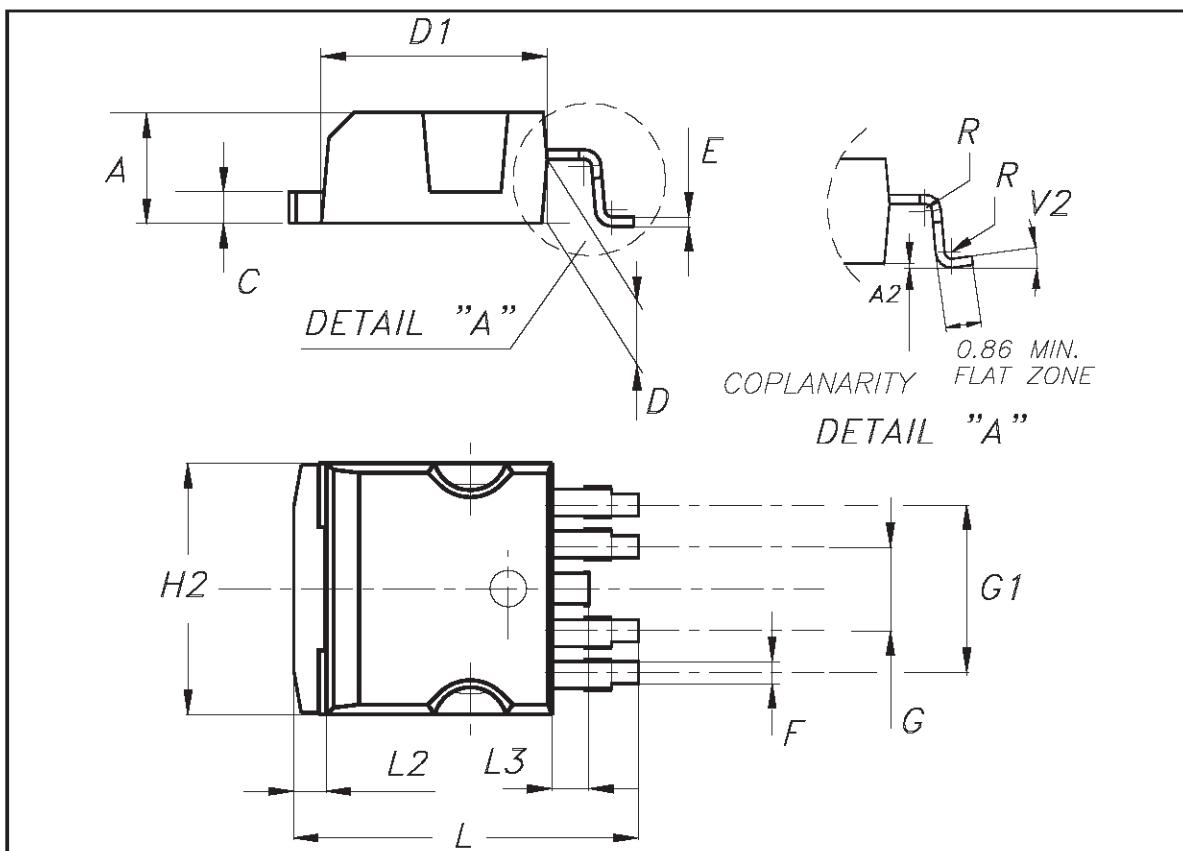
PENTAWATT (VERTICAL) MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			4.8			0.189
C			1.37			0.054
D	2.4		2.8	0.094		0.110
D1	1.2		1.35	0.047		0.053
E	0.35		0.55	0.014		0.022
F	0.8		1.05	0.031		0.041
F1	1		1.4	0.039		0.055
G	3.2	3.4	3.6	0.126	0.134	0.142
G1	6.6	6.8	7	0.260	0.268	0.276
H2			10.4			0.409
H3	10.05		10.4	0.396		0.409
L		17.85			0.703	
L1		15.75			0.620	
L2		21.4			0.843	
L3		22.5			0.886	
L5	2.6		3	0.102		0.118
L6	15.1		15.8	0.594		0.622
L7	6		6.6	0.236		0.260
M		4.5			0.177	
M1		4			0.157	
Diam.	3.65		3.85	0.144		0.152



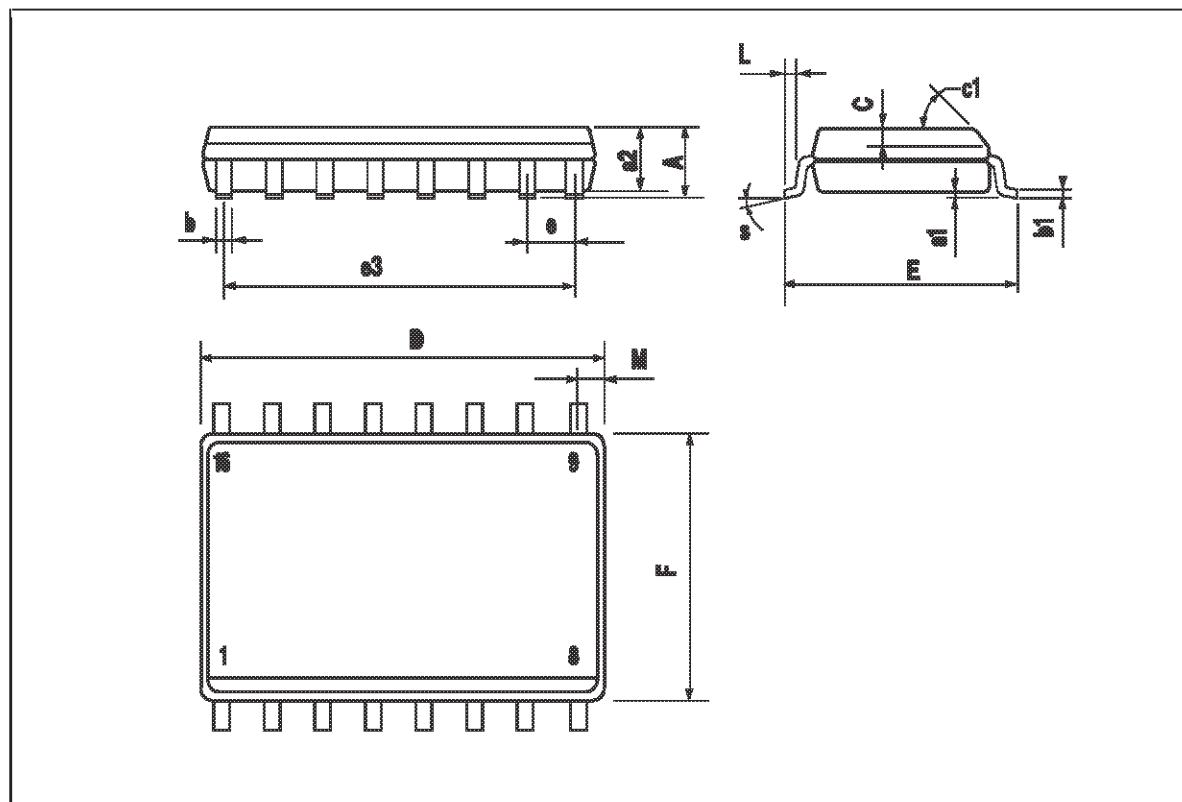
P²PAK MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	4.30		4.80	0.169		0.189
A2	0.03		0.23	0.001		0.009
C	1.17		1.37	0.046		0.054
D	2.40		2.80	0.094		0.110
D1	8.95		9.35	0.352		0.368
E	0.35		0.55	0.014		0.022
F	0.80		1.05	0.031		0.041
G	3.20		3.60	0.126		0.142
G1	6.60		7.00	0.260		0.276
H2			10.40			0.409
L	13.59		14.39	0.535		0.567
L2	1.27		1.40	0.050		0.055
L3	1.30		1.70	0.051		0.067
R		0.30			0.012	
V2	0 d		8 d			



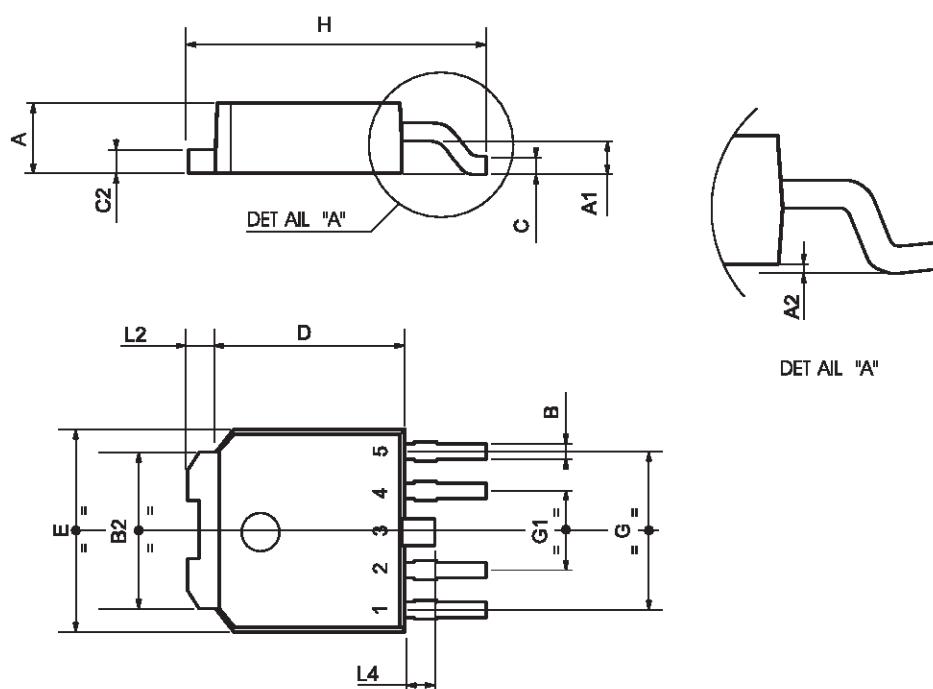
SO-16L MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			2.65			0.104
a1	0.1		0.2	0.004		0.008
a2			2.45			0.096
b	0.35		0.49	0.014		0.019
b1	0.23		0.32	0.009		0.012
C		0.5			0.020	
c1		45° (typ.)				
D	10.1		10.5	0.397		0.413
E	10.0		10.65	0.393		0.419
e		1.27			0.050	
e3		8.89			0.350	
F	7.4		7.6	0.291		0.300
L	0.5		1.27	0.020		0.050
M			0.75			0.029
S		8° (max.)				



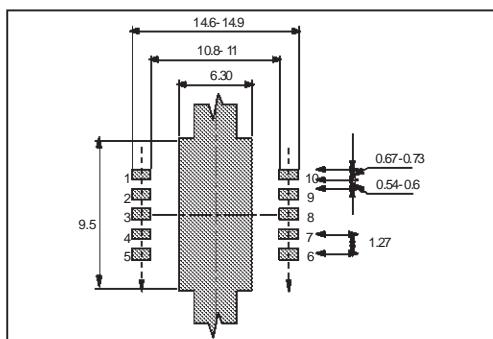
PAAK MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	2.2		2.4	0.086		0.094
A1	0.9		1.1	0.035		0.043
A2	0.03		0.23	0.001		0.009
B	0.4		0.6	0.015		0.023
B2	5.2		5.4	0.204		0.212
C	0.45		0.6	0.017		0.023
C2	0.48		0.6	0.019		0.023
D	6		6.2	0.236		0.244
E	6.4		6.6	0.252		0.260
G	4.9		5.25	0.193		0.206
G1	2.38		2.7	0.093		0.106
H	9.35		10.1	0.368		0.397
L2		0.8	1		0.031	0.039
L4	0.6		1	0.031		0.039

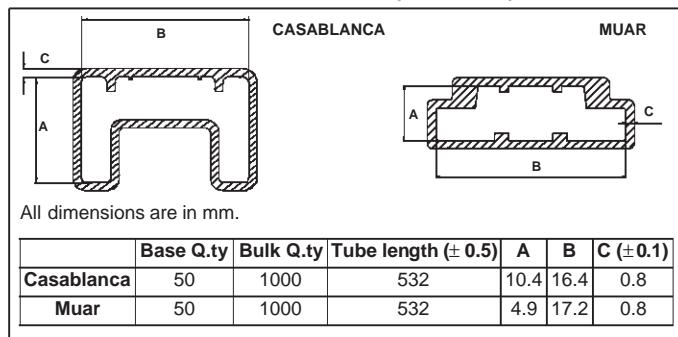


VN820 / VN820SO / VN820SP / VN820-B5 / VN820PT

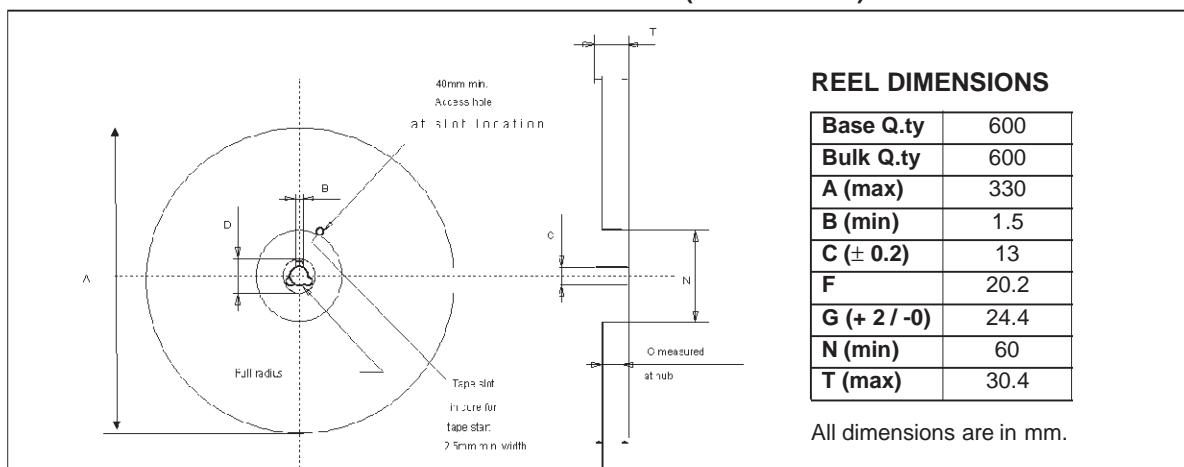
PowerSO-10™ SUGGESTED PAD LAYOUT



TUBE SHIPMENT (no suffix)



TAPE AND REEL SHIPMENT (suffix "13TR")

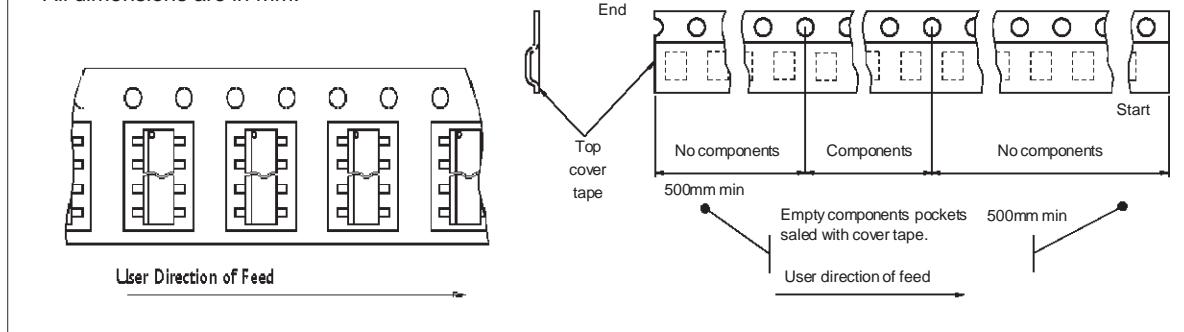
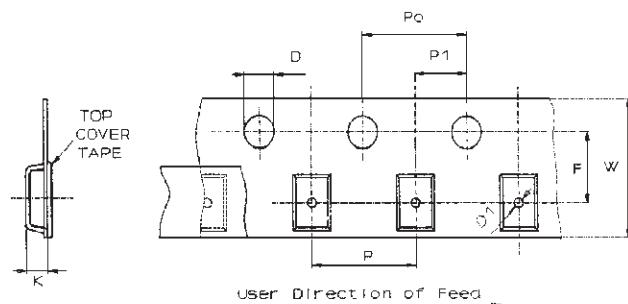


TAPE DIMENSIONS

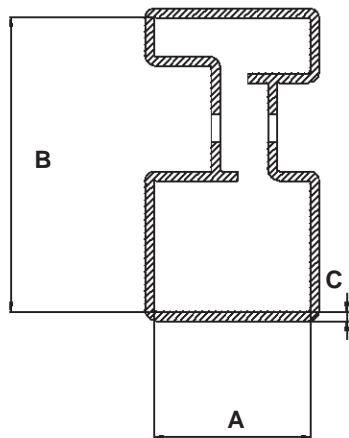
According to Electronic Industries Association (EIA) Standard 481 rev. A, Feb 1986

Tape width	W	24
Tape Hole Spacing	P0 (± 0.1)	4
Component Spacing	P	24
Hole Diameter	D ($\pm 0.1/-0$)	1.5
Hole Diameter	D1 (min)	1.5
Hole Position	F (± 0.05)	11.5
Compartment Depth	K (max)	6.5
Hole Spacing	P1 (± 0.1)	2

All dimensions are in mm.



PENTAWATT TUBE SHIPMENT (no suffix)

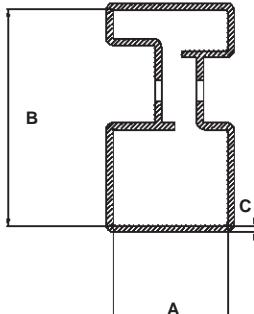


Base Q.ty	50
Bulk Q.ty	1000
Tube length (± 0.5)	532
A	18
B	33.1
C (± 0.1)	1

All dimensions are in mm.

VN820 / VN820SO / VN820SP / VN820-B5 / VN820PT

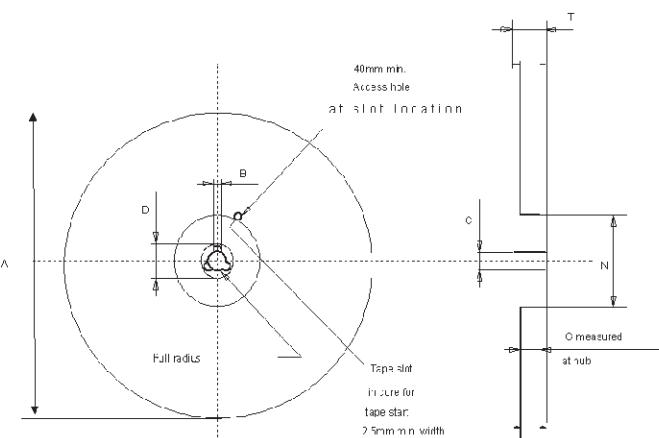
P²PAK TUBE SHIPMENT (no suffix)



Base Q.ty	50
Bulk Q.ty	1000
Tube length (± 0.5)	532
A	18
B	33.1
C (± 0.1)	1

All dimensions are in mm.

TAPE AND REEL SHIPMENT (suffix "13TR")



REEL DIMENSIONS	
Base Q.ty	1000
Bulk Q.ty	1000
A (max)	330
B (min)	1.5
C (± 0.2)	13
F	20.2
G (+ 2 / -0)	24.4
N (min)	60
T (max)	30.4

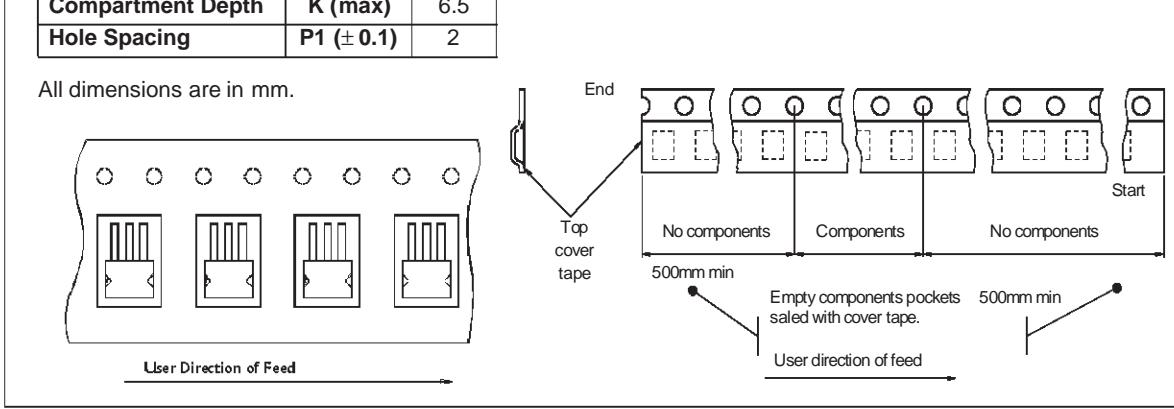
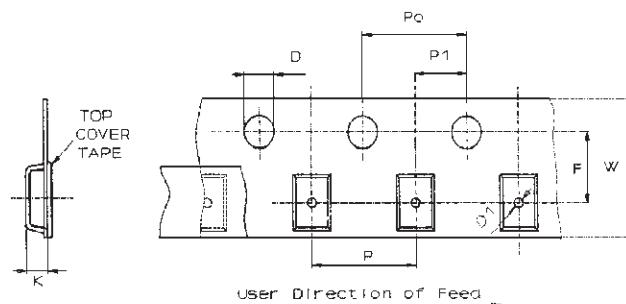
All dimensions are in mm.

TAPE DIMENSIONS

According to Electronic Industries Association (EIA) Standard 481 rev. A, Feb 1986

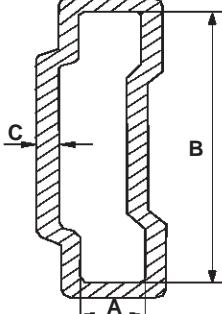
Tape width	W	24
Tape Hole Spacing	P0 (± 0.1)	4
Component Spacing	P	16
Hole Diameter	D ($\pm 0.1/-0$)	1.5
Hole Diameter	D1 (min)	1.5
Hole Position	F (± 0.05)	11.5
Compartment Depth	K (max)	6.5
Hole Spacing	P1 (± 0.1)	2

All dimensions are in mm.



VN820 / VN820SO / VN820SP / VN820-B5 / VN820PT

SO-16L TUBE SHIPMENT (no suffix)



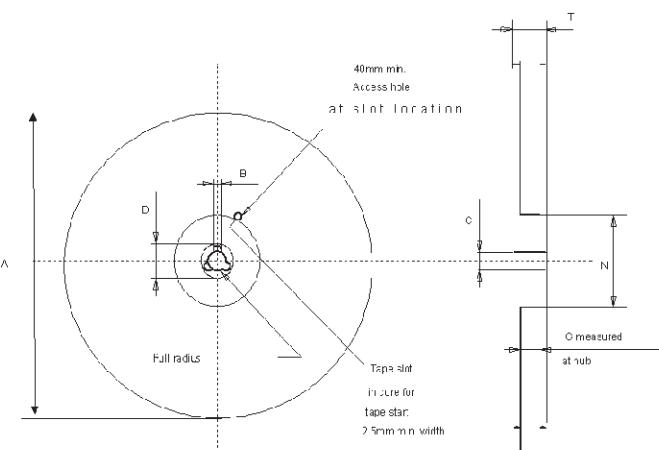
Dimensions:

- A**: 3.5 mm
- B**: 13.8 mm
- C**: 0.6 mm (± 0.1)

Base Q.ty	50
Bulk Q.ty	1000
Tube length (± 0.5)	532
A	3.5
B	13.8
C (± 0.1)	0.6

All dimensions are in mm.

TAPE AND REEL SHIPMENT (suffix "13TR")



Dimensions:

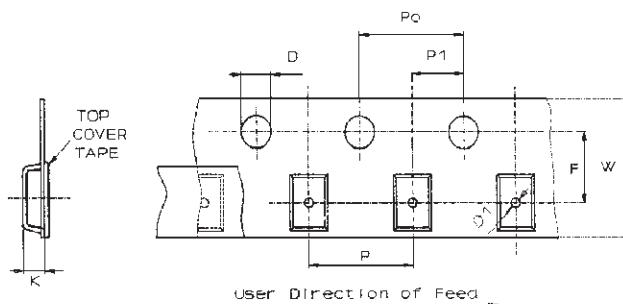
- A**: 13 mm
- B**: 1.5 mm
- C**: 0.6 mm (± 0.1)
- D**: 1.5 mm ($\pm 0.1/-0$)
- E**: 0.6 mm (± 0.1)
- F**: 20.2 mm
- G**: 16.4 mm ($+2/-0$)
- H**: 60 mm (± 0.2)
- I**: 22.4 mm (± 0.2)
- J**: 0.6 mm (± 0.1)
- K**: 6.5 mm (± 0.1)
- L**: 0.6 mm (± 0.1)
- M**: 0.6 mm (± 0.1)
- N**: 0.6 mm (± 0.1)
- O**: 0.6 mm (± 0.1) measured at hub
- P**: 0.6 mm (± 0.1)
- Q**: 0.6 mm (± 0.1)
- R**: 0.6 mm (± 0.1)
- S**: 0.6 mm (± 0.1)
- T**: 0.6 mm (± 0.1)
- U**: 0.6 mm (± 0.1)
- V**: 0.6 mm (± 0.1)
- W**: 0.6 mm (± 0.1)
- X**: 0.6 mm (± 0.1)
- Y**: 0.6 mm (± 0.1)
- Z**: 0.6 mm (± 0.1)

Base Q.ty	1000
Bulk Q.ty	1000
A (max)	330
B (min)	1.5
C (± 0.2)	13
F	20.2
G ($+2/-0$)	16.4
H (min)	60
I (max)	22.4

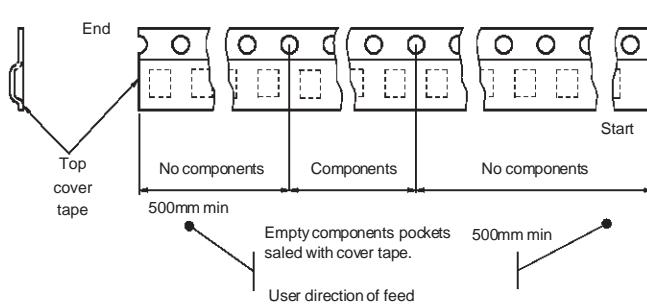
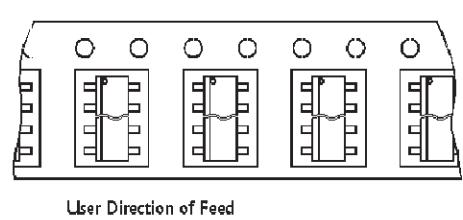
TAPE DIMENSIONS

According to Electronic Industries Association (EIA) Standard 481 rev. A, Feb 1986

Tape width	W	16
Tape Hole Spacing	P0 (± 0.1)	4
Component Spacing	P	12
Hole Diameter	D ($\pm 0.1/-0$)	1.5
Hole Diameter	D1 (min)	1.5
Hole Position	F (± 0.05)	7.5
Compartment Depth	K (max)	6.5
Hole Spacing	P1 (± 0.1)	2

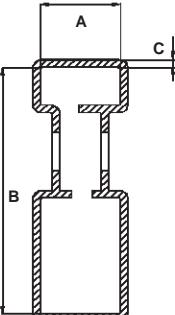


All dimensions are in mm.



VN820 / VN820SO / VN820SP / VN820-B5 / VN820PT

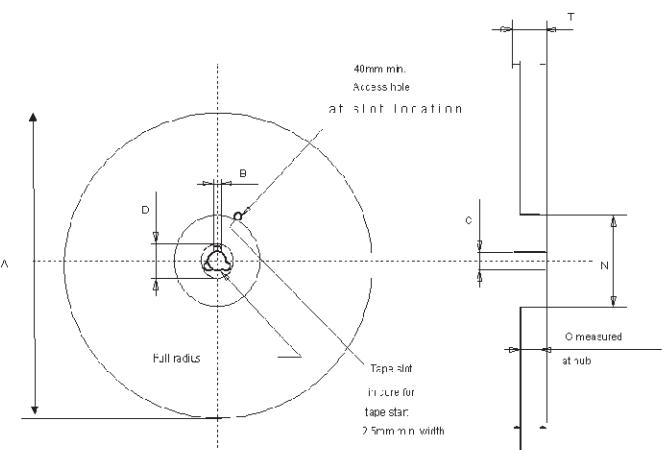
PPAK TUBE SHIPMENT (no suffix)



Base Q.ty	75
Bulk Q.ty	3000
Tube length (± 0.5)	532
A	6
B	21.3
C (± 0.1)	0.6

All dimensions are in mm.

TAPE AND REEL SHIPMENT (suffix "13TR")



REEL DIMENSIONS	
Base Q.ty	2500
Bulk Q.ty	2500
A (max)	330
B (min)	1.5
C (± 0.2)	13
F	20.2
G ($+2/-0$)	16.4
N (min)	60
T (max)	22.4

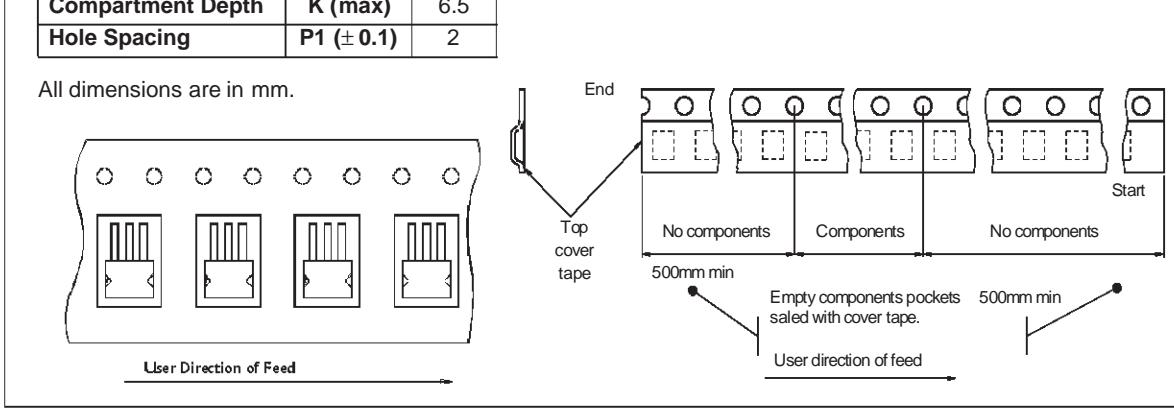
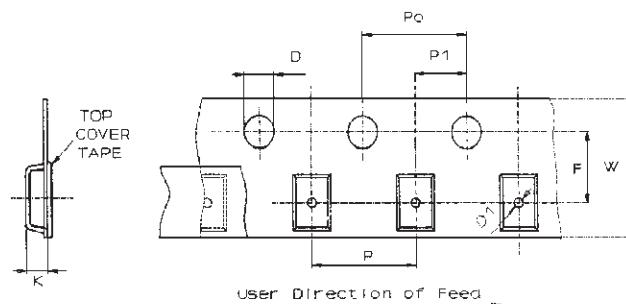
All dimensions are in mm.

TAPE DIMENSIONS

According to Electronic Industries Association (EIA) Standard 481 rev. A, Feb 1986

Tape width	W	16
Tape Hole Spacing	P0 (± 0.1)	4
Component Spacing	P	8
Hole Diameter	D ($\pm 0.1/-0$)	1.5
Hole Diameter	D1 (min)	1.5
Hole Position	F (± 0.05)	7.5
Compartment Depth	K (max)	6.5
Hole Spacing	P1 (± 0.1)	2

All dimensions are in mm.



Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

The ST logo is a trademark of STMicroelectronics

© 2000 STMicroelectronics - Printed in ITALY- All Rights Reserved.

STMicroelectronics GROUP OF COMPANIES

Australia - Brazil - China - Finland - France - Germany - Hong Kong - India - Italy - Japan - Malaysia - Malta -
Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - U.S.A.

<http://www.st.com>